Atto Docket No.: 436589 Express Mail Label No.: EV413219918US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

10/535,688	Group Art No.	Not Yet Assigned
May 19, 2005	Confirmation No.	4283
Surface-Emitting Semi-Conductor Lasers Having Buried Tunnel Junctions and Methods of Producing Same		December 28, 2005
	May 19, 2005 Surface-Emitting Semi-Conductor Lasers Having Buried Tunnel Junctions and Methods of Producing	May 19, 2005 Surface-Emitting Semi-Conductor Lasers Having Buried Tunnel Junctions and Methods of Producing Same

Commissioner For Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

INFORMATION DISCLOSURE STATEMENT TRANSMITTAL

This Information Disclosure Statement is submitted:

| under 37 CFR 1.97(b), or (Within three months of filing national application, or date of entry of national application, or before mailing date of first office action on the merits, whichever occurs last)

| under 37 CFR 1.97(c) together with either a:
| Statement under 37 CFR 1.97(e), or
| a \$180 fee under 37 CFR 1.17(p), or
| (After the CFR 1.97(b) time period, but before final action or notice of allowance, which ever occurs first)

| under 37 CFR 1.97(d) together with a:
| Statement under 37 CFR 1.97(e)(1) or (2), and
| a \$180.00 fee set forth in 37 CFR 1.17(p).
| (Filed after final action, a notice of allowance, on or before payment of issue fee)

Please charge to Deposit Account 12-0600 the sum of \$0.00. At any time during the pendency of this application, please charge any fees required or credit any overpayment to Deposit Account 12-0600 pursuant to 37 CFR 1.25.

Applicant(s) submit herewith Form PTO 1449 – Information Disclosure Statement together with copies of non-U.S. patents, publications or other information (if any) of which applicant(s) are aware, which applicant(s) believe(s) may be material to the examination of the application and for which there may be a duty to disclose in accordance with 37 CFR 1.56.

A concise explanation of the relevance of foreign language patents, foreign language publications and other foreign language information listed on PTO Form 1449, as presently understood by the individual(s) designated in 37 CFR 1.56(c) most knowledgeable about the content is given on the attached sheet, or where a foreign language patent is cited in

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a search report or other action by a foreign patent office in a counter part foreign application, an English language version of the search report or action which indicates the degree of relevance found by the foreign office is listed on form PTO 1449 and is enclosed herewith.

It is requested that the information disclosed herein be made of record in this application.

Respectfully submitted,

LATHROP & GAGE LC

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PTO/SB/08a (08-03)

Approved for use through 07/31/2006. OMB 0651-0031

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Substitute	e for form 1449A/PTC		ACCULATION OF THE PARTY OF THE	Complete if Known			
		Application Number	10/468,183				
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Filing Date	April 28, 2004				
		First Named Inventor	Markus-Christian Amann				
JIA				Art Unit	2828		
	(Use as many she	ets as	necessary)	Examiner Name	Minsun Oh Harvey		
Sheet	1	of	2	Attorney Docket Number	411883		

U.S. PATENT DOCUMENTS							
Examiner Cite		Document Number	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
Initials *	Cite No.1	Number - Kind Code ² (if known)	MM-DD-YYYY		Figures Appear		
		US-5,661,075	08-26-1997	Grodzinski, et al.			
		US- 6,052,398	04-18-2000	Brillouet, et al.			
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-	FOREIGN PATENT DOCUMENTS						
		Foreign Patent Document			Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
Examiner Cite No.1	Country Code ³ - Number ⁴ - Kind Code ⁵ (<i>if known</i>)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Т ⁶			
		DE 101 07 349 A1	08-29-2002	Amann, Markus-Christian			
	-	WO 98/07218 A	02-19-1998	Gore & Associates, Inc.			
		EP 0 184 117 A	06-11-1986	Siemens Ag			
	-						

Examiner Signature	Date Considered	

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This collection of information is required by 37 CER 1.97 cod 1.09. The information is continued to applicant. *In the continued to applicant in the continued to applicant. *In the continued to a

Translation is attached.

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Substitute for form 1449B/PTO				Complete if Known			
INICO	DRAKTION	ם ו	OLOCUDE	Application Number	10/468,183		
			CLOSURE	Filing Date	April 28, 2004		
SIA	IEMENTE	BY A	PPLICANT	First Named Inventor	Markus-Christian Amann		
				Art Unit	2828		
	(Use as many st	neets as	necessary)	Examiner Name	Minsun Oh Harvey		
Sheet	2	of	2	Attorney Docket Number	411883		

Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	τ;
		ORTSIEFER, M, et al.: "Low-Threshold Index-Guided 1.5 Mum Long-Wavelenght Vertical-Cavity Surface- Emitting Laser With High Efficiency", Applied Physics Letters, American Institute of Physics, New York, US, pg. 2179-2181, April 17, 2000	
		NAKAGAWA, S., et al.: "88° Continuous-Wave Operation Of Apertured, Intracavity Contacted, 1.55 Mum Vertical-Cavity Surface-Emitting Lasers" Applied Physics Letters, American Institute of Physics, New York, US, pg 1337-1339, March 5, 2001	
		ORTSIEFER, M., et al: "Submilliamp Long-Wavelength InP-Based Vertical-Cavity Surface-Emitting Laser With Stable Linear Polarisation" Electronics Letters, IEE Stevenage, pg. 1124-1126, June 22, 2000	
		ORTSIEFER, M, et al: "90°C Continuous-Wave Operation Of 1.83-Mum Vertical-Cavity Surface-Emitting Lasers" IEEE Photonics Technology Letters, IEE Inc., New York, US, pgs 1435-1437, November 2000	
		SCHRAUD, G, et al: "Substrateless Singlemode Vertical Cavity Surface-Emitting GaAs/GaALAs Laser Diode" Electronics Letters, IEE Stevenage, GB, pgs 238-239, February 3, 1994	
		LIAU, Z.L., et al: "A Novel Technique For Gainasp/Inp Buried Heterostructure Laser Fabrication" Applied Physics Letters, American Institute of Physics, New York, US, pg 568-570, April 1, 1982	
		International Preliminary Examination Report for PCT/EP2003/012433	
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Examiner	Date	
	Date	
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance

^{*}EXAMINEH: Initial ir reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Applicant's unique citation designation number (optional). Applicant is to place a check mark here if English language Translation is attached. This collection of information is required by 37 CFR 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 120 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.